

isc Silicon NPN Power Transistor

2SD1848

DESCRIPTION

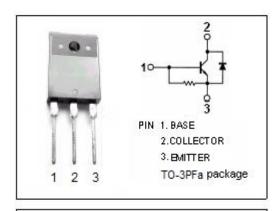
- · Collector-Base Breakdown Voltage-
 - : V_{CBO}= 1300V (Min.)
- · High Switching Speed
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

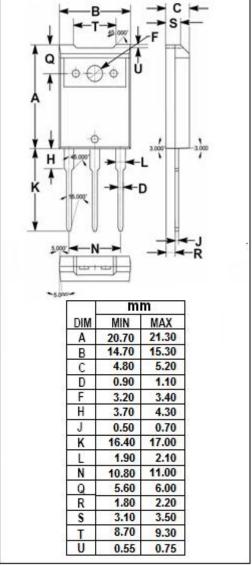
APPLICATIONS

• Designed for horizontal deflection output applications

ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector- Base Voltage	1300	V
V _{CES}	Collector-Emitter Voltage	1300	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	6	Α
I _{CM}	Collector Current-Peak	18	Α
l _Β	Base Current- Continuous	2.5	А
P _C	Collector Power Dissipation @ T _a =25°C	3	
	Collector Power Dissipation @ T _c =25 °C	100	W
Тл	Junction Temperature 150		$^{\circ}$ C
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

1c-25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I _E = 200mA; I _C = 0	7			V			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1.2A			8.0	V			
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1.2A			1.5	V			
I _{CBO}	Collector Cutoff Current	V _{CB} = 750V; I _E = 0 V _{CB} = 1300V; I _E = 0			10 1.0	μA mA			
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 5V	5		25				
h _{FE-2}	DC Current Gain	I _C = 5A; V _{CE} = 10V	4.5						
f⊤	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 10V		2		MHz			
V _{ECF}	C-E Diode Forward Voltage	I _F = 6A			2.3	V			
Switching times, Resistive Load									
t _{stg}	Storage Time	I _C = 5A; I _{B1} = 1.2A; I _{B2} = -2.4A;		1.5		μ \$			
t _f	Fall Time	V _{CC} = 200V		0.2		μS			

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